

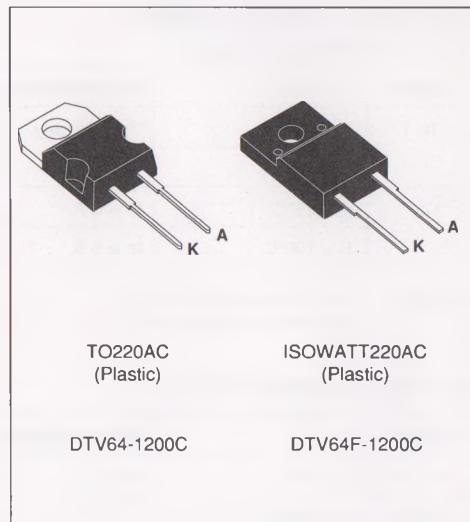


## FEATURES

- HIGH BREAKDOWN VOLTAGE CAPABILITY
- MEDIUM & HIGH FREQUENCY OPERATION
- SPECIFIED TURN ON SWITCHING CHARACTERISTICS
- TYPICAL TOTAL LOSSES : 3 W  
( $I_{Fpeak} = 6 \text{ A}$ ,  $F = 64 \text{ kHz}$ )
- SUITABLE WITH **BUH** TRANSISTORS SERIES
- INSULATED VERSION (ISOWATT220AC) :  
Insulating voltage = 2000 V DC  
Capacitance = 12 pF

## DESCRIPTION

High voltage diode especially designed for horizontal deflection stage in standard and high resolution displays for TV's and monitors.  
This device is packaged in TO220AC or ISO-WATT220AC.



## ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter			Value	Unit
$V_{RRM}$	Repetitive peak reverse voltage			1200	V
$V_{RWM}$	Repetitive working voltage			1200	V
$I_F(\text{RMS})$	RMS forward current			20	A
$I_F(\text{AV})$	$\delta = 0.5$	TO220AC	$T_c=120^\circ\text{C}$	6	A
		ISOWATT220AC	$T_c=90^\circ\text{C}$	6	
$I_{FSM}$	Surge non repetitive forward current		$t_p=10\text{ms}$ sinusoidal	100	A
$T_{stg}$ $T_j$	Storage and junction temperature range			- 40 to + 150	°C

## THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
R <sub>th</sub> (j-c)	Junction to case	TO220AC	2.2
		ISOWATT220AC	5.0

## ELECTRICAL CHARACTERISTICS

## STATIC CHARACTERISTICS

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
I <sub>R</sub> *	T <sub>j</sub> = 25°C	V <sub>R</sub> = V <sub>RWM</sub>				200	μA
	T <sub>j</sub> = 100°C					2.0	mA
V <sub>F</sub> **	T <sub>j</sub> = 25°C	I <sub>F</sub> = 6 A				2.0	V
	T <sub>j</sub> = 100°C	I <sub>F</sub> = 6 A				1.8	

Pulse test : \* tp = 5 ms, duty cycle &lt; 2 %

\*\* tp = 380 μs, duty cycle &lt; 2 %

## RECOVERY CHARACTERISTICS

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
trr (1)	T <sub>j</sub> = 25°C	I <sub>F</sub> = 1 A V <sub>R</sub> = 30 V	dI <sub>F</sub> /dt = -50 A/μs dI <sub>F</sub> /dt = -15 A/μs			100	ns
trr (1)	T <sub>j</sub> = 100°C					120	ns
trr	T <sub>j</sub> = 25°C	I <sub>F</sub> = 100mA	I <sub>R</sub> = 100mA		70		ns

## TURN ON SWITCHING CHARACTERISTICS

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
t <sub>FR</sub> (2)	T <sub>j</sub> = 100°C	I <sub>F</sub> = 6 A	dI <sub>F</sub> /dt = 80 A/μs		0.5		μs
V <sub>FP</sub> (2)		V <sub>FR</sub> = 1.1 x V <sub>F</sub>			27		V

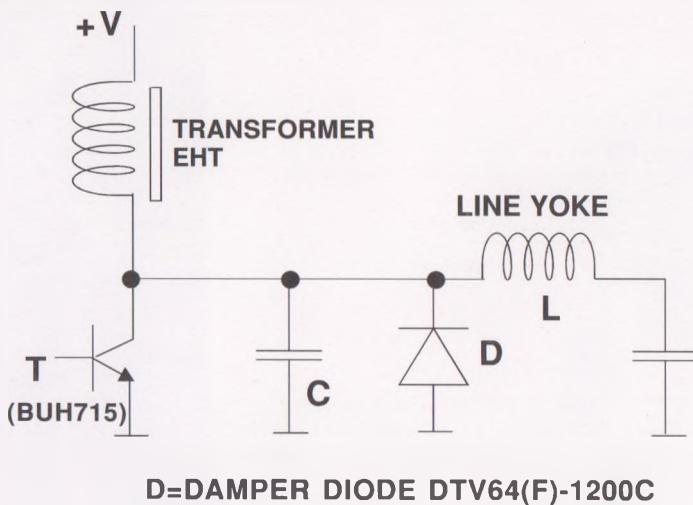
(1) Test following Jedec Standard

(2) Test representative of the application

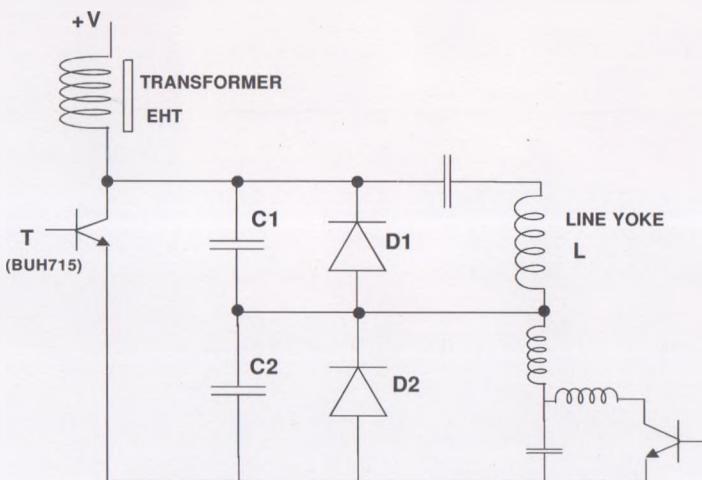
To evaluate the conduction losses use the following equations :

$$V_F = 1.5 + 0.050 I_F \quad P = 1.5 \times I_{F(AV)} + 0.050 \times I_{F^2(RMS)}$$

## BASIC HORIZONTAL DEFLECTION CIRCUIT



## BASIC E-W DIODE MODULATOR CIRCUIT



D1=DTV64(F)-1200C

D2=STTB506D/F